

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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EFC6601R

N-Channel Power MOSFET 24V, 13A, 11.5m Ω , Dual EFCP



http://onsemi.com

Features

- 2.5V drive
- · Common-drain type
- · 2KV ESD HBM

- · Protection diode in
- · Halogen free compliance

Specifications

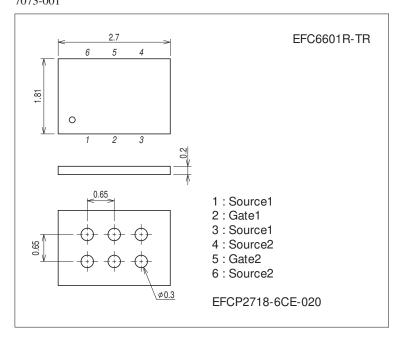
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Source-to-Source Voltage	Vsss		24	V
Gate-to-Source Voltage	VGSS		±12	V
Source Current (DC)	IS		13	Α
Source Current (Pulse)	ISP	PW≤10μs, duty cycle≤1%	60	Α
Total Dissipation	PT	When mounted on ceramic substrate (5000mm ² ×0.8mm)	2.0	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ) 7073-001

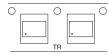


Product & Package Information

Package : EFCPJEITA, JEDEC :-

• Minimum Packing Quantity : 5,000 pcs./reel

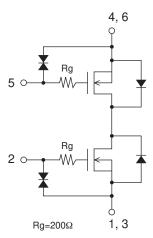
Taping Type: TR



Marking



Electrical Connection



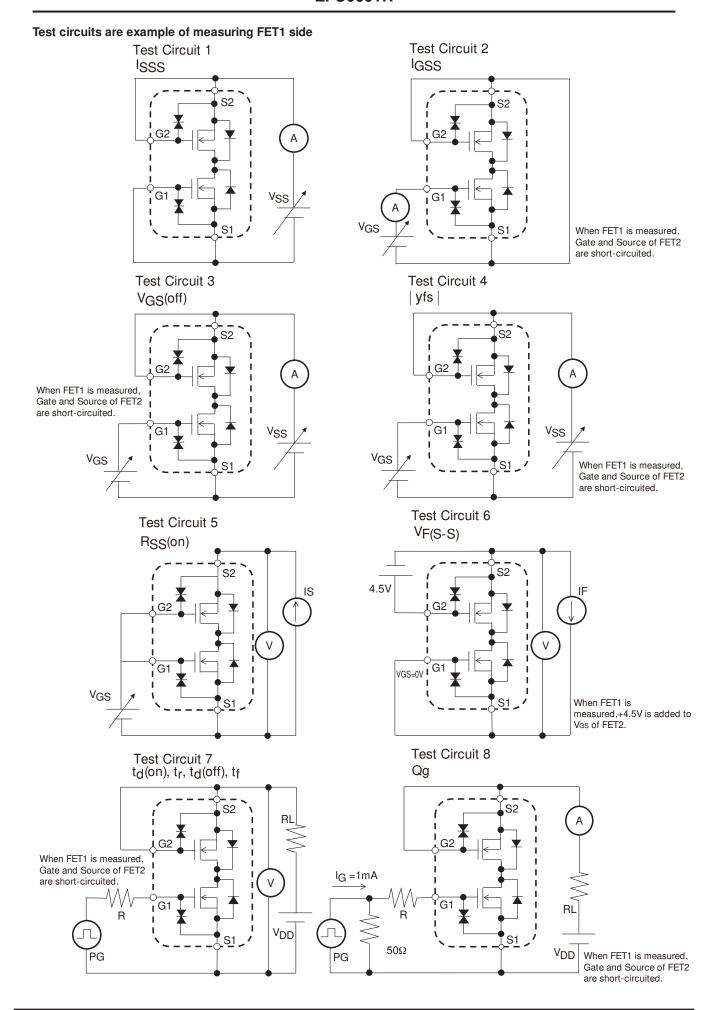
EFC6601R

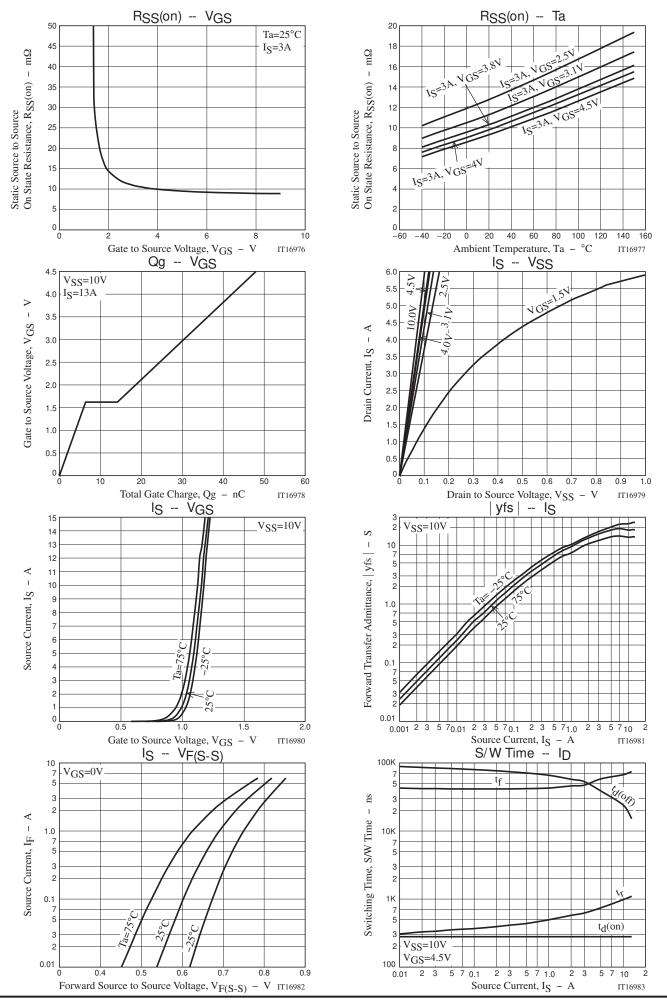
Electrical Characteristics at Ta=25°C

Parameter	Cumbal	Conditions		Ratings			Lloit
Parameter	Symbol			min	typ	max	Unit
Source-to-Source Breakdown Voltage	V(BR)SSS	IS=1mA, VGS=0V	Test Circuit 1	24			V
Zero-Gate Voltage Source Current	ISSS	V _{SS} =20V, V _{GS} =0V	Test Circuit 1			1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±8V, VSS=0V	Test Circuit 2			±1	μΑ
Cutoff Voltage	V _{GS} (off)	V _{SS} =10V, I _S =1mA	Test Circuit 3	0.5		1.3	٧
Forward Transfer Admittance	yfs	VSS=10V, IS=3A	Test Circuit 4		15.5		S
	Rss(on)1	I _S =3A, V _{GS} =4.5V	Test Circuit 5	6.6	9.5	11.5	mΩ
Static Source-to-Source On-State Resistance	R _{SS} (on)2	I _S =3A, V _{GS} =4.0V	Test Circuit 5	7.0	10	12	mΩ
	R _{SS} (on)3	I _S =3A, V _{GS} =3.8V	Test Circuit 5	7.3	10.5	13	mΩ
	Rss(on)4	IS=3A, VGS=3.1V	Test Circuit 5	8.0	11.5	15	mΩ
	Rss(on)5	IS=3A, VGS=2.5V	Test Circuit 5	9.0	13	17	mΩ
Turn-ON Delay Time	t _d (on)		Test Circuit 7		280		ns
Rise Time	t _r	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\			630		ns
Turn-OFF Delay Time	t _d (off)	V _{DD} =10V, V _{GS} =4.5V, I _S =3A			53000		ns
Fall Time	tf				47000		ns
Total Gate Charge	Qg	V _{DD} =10V, V _{GS} =4.5V, I _S =13A	Test Circuit 8		48		nC
Forward Source-to-Source Voltage	VF(S-S)	I _S =3A, V _{GS} =0V	Test Circuit 6		0.76	1.2	٧

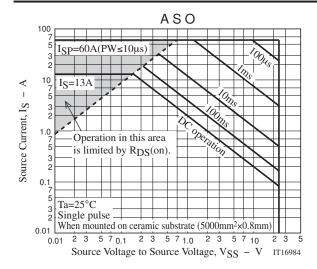
Ordering Information

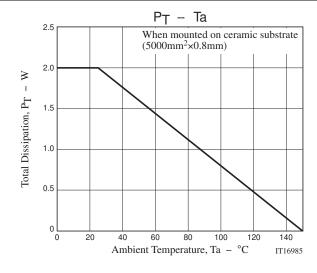
Device	Package	Shipping	memo	
EFC6601R-TR	C6601R-TR EFCP		Pb Free and Halogen Free	





EFC6601R

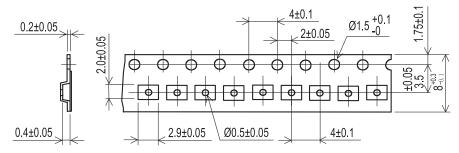




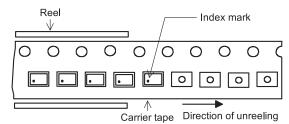
Taping Specification

EFC6601R-TR

- 1. Taping Configuration
 - 1-1 .Carrier Tape Size (unit:mm)

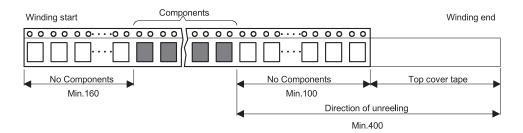


1-2 .Device Placement Direction



Packing type····TR

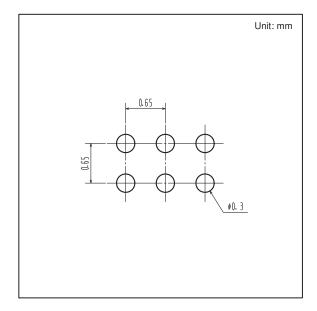
1-3 .Leader portion and Trailer portion (unit:mm)



Outline Drawing

EFC6601R-TR

Land Pattern Example



Note on usage: Since the EFC6601R is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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